

High Speed IR Emitting Diode in T-1¾ Package

Description

TSHG6400 is a high speed infrared emitting diode in GaAlAs double hetero (DH) technology, molded in a clear, untinted plastic package.

TSHG6000 series combines high speed with high radiant power at wavelength of 850 nm.



Features

- · High modulation bandwidth
- Extra high radiant power and radiant intensity
- · Low forward voltage
- Suitable for high pulse current operation
- Standard package T-1¾ (Ø 5 mm)
- Angle of half intensity $\varphi = \pm 22^{\circ}$
- Peak wavelength $\lambda_p = 850 \text{ nm}$
- High reliability
- Good spectral matching to Si photodetectors
- Lead (Pb)-free component
- Component in accordance to ELV 2000/53/EC, RoHS 2002/95/EC and WEEE 2002/96/EC

Applications

 Infrared radiation source for CMOS cameras (illumination). High speed IR data transmission.

Parts Table

Part	Remarks		
TSHG6400	MOQ: 4000 pc		

Absolute Maximum Ratings

T_{amb} = 25 °C, unless otherwise specified

Parameter	Test condition	Symbol	Value	Unit
Reverse voltage		V _R	5	V
Forward current		I _F	100	mA
Peak forward current	$t_p/T = 0.5$, $t_p = 100 \mu s$	I _{FM}	200	mA
Surge forward current	t _p = 100 μs	I _{FSM}	1	А
Power dissipation		P _V	250	mW
Junction temperature		T _j	100	°C
Operating temperature range		T _{amb}	- 40 to + 85	°C
Storage temperature range		T _{stg}	- 40 to + 100	°C
Soldering temperature	$t \le 5$ sec, 2 mm from case	T _{sd}	260	°C
Thermal resistance junction/ ambient		R _{thJA}	300	K/W

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Basic Characteristics

 T_{amb} = 25 °C, unless otherwise specified

Parameter	Test condition	Symbol	Min	Тур.	Max	Unit
Forward voltage	$I_F = 100 \text{ mA}, t_p = 20 \text{ ms}$	V _F		1.5	1.8	V
	$I_F = 1 \text{ A}, t_p = 100 \mu \text{s}$	V _F		2.3		V
Temp. coefficient of V _F	I _F = 100 mA	TK _{VF}		- 2.1		mV/K
Reverse current	V _R = 5 V	I _R			10	μΑ
Junction capacitance	$V_R = 0 \text{ V, } f = 1 \text{ MHz, } E = 0$	C _j		125		pF
Radiant intensity	$I_F = 100 \text{ mA}, t_p = 20 \text{ ms}$	l _e	40	70	200	mW/sr
	$I_F = 1 \text{ A}, t_p = 100 \mu \text{s}$	l _e		700		mW/sr
Radiant power	$I_F = 100 \text{ mA}, t_p = 20 \text{ ms}$	φ _e		50		mW
Temp. coefficient of ϕ_e	I _F = 100 mA	TKφ _e		- 0.35		%/K
Angle of half intensity		φ		± 22		deg
Peak wavelength	I _F = 100 mA	λ_{p}		850		nm
Spectral bandwidth	I _F = 100 mA	Δλ		40		nm
Temp. coefficient of λ_p	I _F = 100 mA	TKλ _p		0.25		nm/K
Rise time	I _F = 100 mA	t _r		20		ns
Fall time	I _F = 100 mA	t _f		13		ns
Cut-off frequency	I_{DC} = 70 mA, I_{AC} = 30 mA pp	f _c		20		MHz
Virtual source diameter		Ø		3.7		mm

Typical Characteristics

Tamb = 25 °C, unless otherwise specified

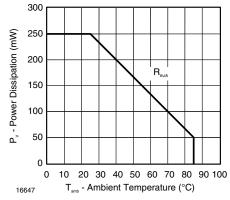


Figure 1. Power Dissipation vs. Ambient Temperature

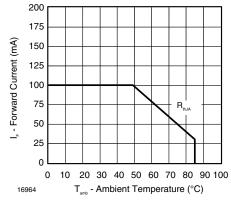


Figure 2. Forward Current vs. Ambient Temperature



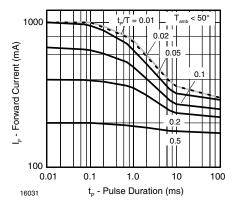


Figure 3. Pulse Forward Current vs. Pulse Duration

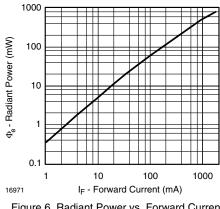


Figure 6. Radiant Power vs. Forward Current

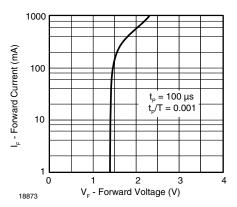


Figure 4. Forward Current vs. Forward Voltage

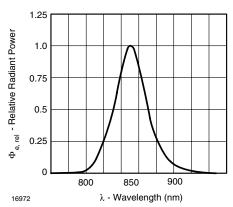


Figure 7. Relative Radiant Power vs. Wavelength

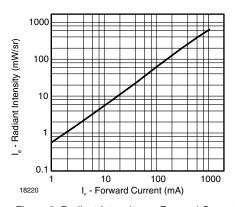


Figure 5. Radiant Intensity vs. Forward Current

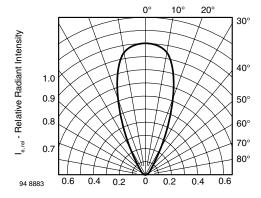
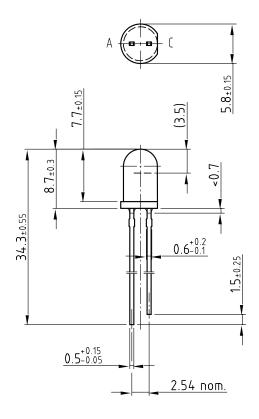
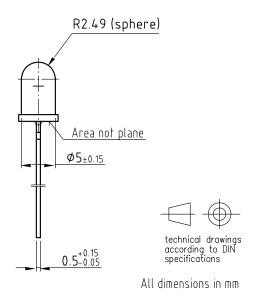


Figure 8. Relative Radiant Intensity vs. Angular Displacement

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Package Dimensions in mm





Drawing-No.: 6.544-5259.06-4

Issue: 5; 27.09.05

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Ozone Depleting Substances Policy Statement

It is the policy of Vishay Semiconductor GmbH to

- 1. Meet all present and future national and international statutory requirements.
- 2. Regularly and continuously improve the performance of our products, processes, distribution and operating systems with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.

It is particular concern to control or eliminate releases of those substances into the atmosphere which are known as ozone depleting substances (ODSs).

The Montreal Protocol (1987) and its London Amendments (1990) intend to severely restrict the use of ODSs and forbid their use within the next ten years. Various national and international initiatives are pressing for an earlier ban on these substances.

Vishay Semiconductor GmbH has been able to use its policy of continuous improvements to eliminate the use of ODSs listed in the following documents.

- 1. Annex A, B and list of transitional substances of the Montreal Protocol and the London Amendments respectively
- 2. Class I and II ozone depleting substances in the Clean Air Act Amendments of 1990 by the Environmental Protection Agency (EPA) in the USA
- 3. Council Decision 88/540/EEC and 91/690/EEC Annex A, B and C (transitional substances) respectively.

Vishay Semiconductor GmbH can certify that our semiconductors are not manufactured with ozone depleting substances and do not contain such substances.

> We reserve the right to make changes to improve technical design and may do so without further notice.

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Document Number 84636 www.vishay.com Rev. 1.0, 28-Nov-06



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Revision: 18-Jul-08

Document Number: 91000 www.vishay.com